imall

Chipsmall Limited consists of a professional team with an average of over 10 year of expertise in the distribution of electronic components. Based in Hongkong, we have already established firm and mutual-benefit business relationships with customers from, Europe, America and south Asia, supplying obsolete and hard-to-find components to meet their specific needs.

With the principle of "Quality Parts, Customers Priority, Honest Operation, and Considerate Service", our business mainly focus on the distribution of electronic components. Line cards we deal with include Microchip, ALPS, ROHM, Xilinx, Pulse, ON, Everlight and Freescale. Main products comprise IC, Modules, Potentiometer, IC Socket, Relay, Connector. Our parts cover such applications as commercial, industrial, and automotives areas.

We are looking forward to setting up business relationship with you and hope to provide you with the best service and solution. Let us make a better world for our industry!



Contact us

Tel: +86-755-8981 8866 Fax: +86-755-8427 6832 Email & Skype: info@chipsmall.com Web: www.chipsmall.com Address: A1208, Overseas Decoration Building, #122 Zhenhua RD., Futian, Shenzhen, China





Bi-directional Low Capacitance TVS Diode

- ESD / transient protection of high-speed data lines in 3.3 / 5 / 12 V applications according to: IEC61000-4-2 (ESD): ±18 kV (air) ±15 kV (contact) IEC61000-4-4 (EFT): 40 A (5 / 50 ns)
- Extremely small form factor down to 0.62 x 0.32 x 0.31 mm³ (0201)
- Max. working voltage: -8 / +14 V
- Very low reverse current < 1 nA typ.
- Very low series inductance down to 0.2 nH typ.
- Low capacitance of 4 pF typ.
- Pb-free (RoHS compliant) package
- Qualified according AEC Q101

Applications

- USB 2.0, 10/100 Ethernet, Firewire, DVI
- Mobile communication
- Consumer products (STB, MP3, DVD, DSC...)
- LCD displays, camera
- Notebooks and destop computers, peripherals



ESD8V0R1B-02LS ESD8V0R1B-02LRH



Туре	Package	Configuration	Marking	
ESD8V0R1B-02LRH	TSLP-2-17	1 line, bi-directional	E	
ESD8V0R1B-02LS	TSSLP-2-1	1 line, bi-directional	E	





Maximum Ratings at $T_A = 25^{\circ}$ C, unless otherwise specified

Parameter	Symbol	Value	Unit	
ESD discharge ¹⁾	V _{ESD}		kV	
air		18		
contact		15		
Peak pulse current ($t_p = 8 / 20 \ \mu s$) ²⁾	I _{pp}	1	А	
Operating temperature range	T _{op}	-55150	°C	
Storage temperature	T _{stg}	-65150		

Electrical Characteristics at $T_A = 25^{\circ}C$, unless otherwise specified

Parameter	Symbol	Values			Unit
		min.	typ.	max.]
Characteristics					
Reverse working voltage, from pin 2 to 1	V _{RWM}	-8	-	14	V
Breakdown voltage	V _(BR)				
$I_{(BR)}$ = 1 mA, from pin 2 to 1		14.5	17	20	
$I_{(BR)}$ = 1 mA, from pin 1 to 2		8.5	11	14	
Reverse current	I _R	-	<1	50	nA
V _R = 3.3 V					
Clamping voltage	V _{CL}				V
$I_{\rm PP}$ = 1 A, $t_{\rm P}$ = 8/20 µs, from pin 2 to 1 ²)		-	23	28	
$I_{\rm PP}$ = 1 A, $t_{\rm P}$ = 8/20 µs, from pin1 to 2 ²)		-	17	22	
Line capacitance	CT	-	4	7	pF
<i>V</i> _R = 0 V, <i>f</i> = 1 MHz					
Series inductance	LS				nH
ESD8V0R1B-02LS		-	0.2	-	
ESD8V0R1B-02LRH		-	0.4	-	

 $^{1}V_{\text{ESD}}$ according to IEC61000-4-2

 $^2\textit{I}_{pp}$ according to IEC61000-4-5



Non-repetitive peak pulse power

Power derating curve $P_{pk} = f(T_A)$

110 %

90

80

70

60

50

40

30

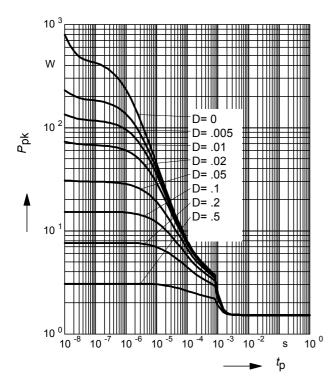
20

10

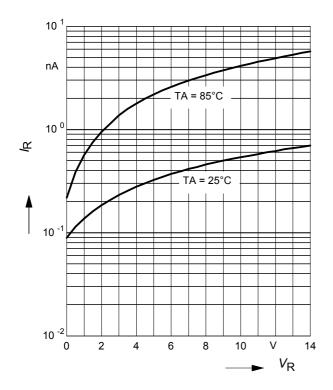
0└ 0

Ppk or /pp

$$P_{pk} = f(t_p)$$



Reverse current $I_{R} = f(V_{R})$ T_{A} = Parameter



Diode capacitance $C_T = f(V_R)$ f = 1MHz

50

75

100

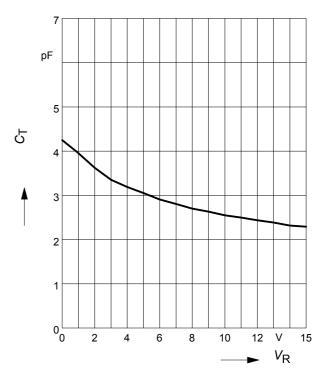
°C

-

 T_{A}

150

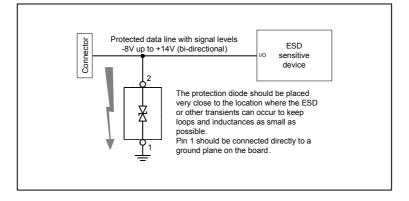
25



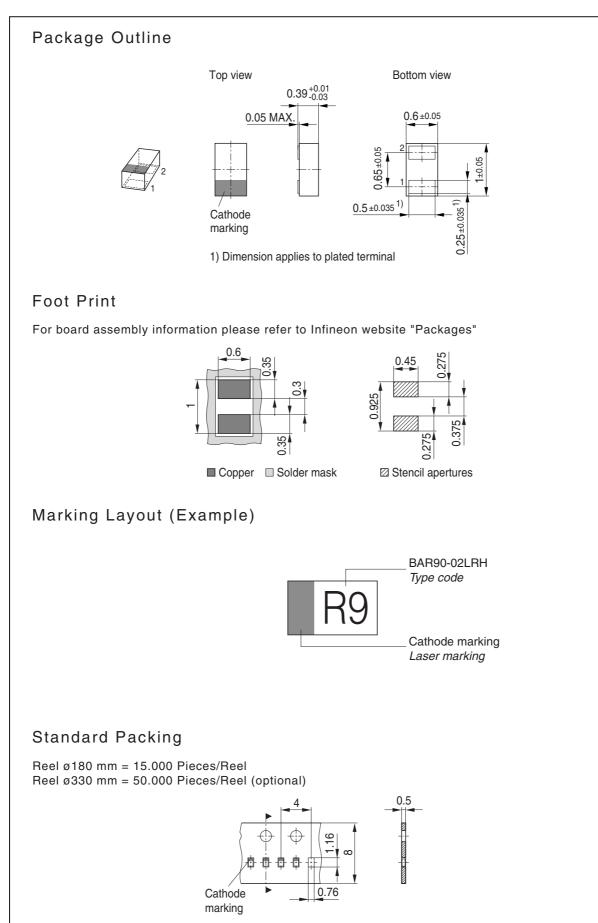


Application example ESD8V0R1B...

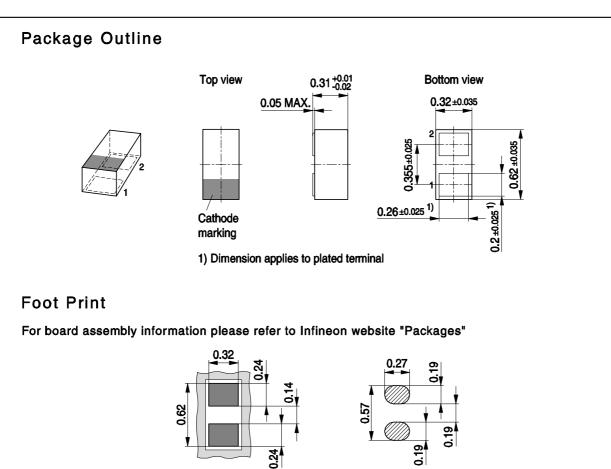
1 line, bi-directional







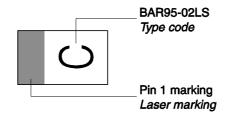




Copper Solder mask

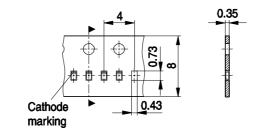


Marking Layout (Example)



Standard Packing

Reel ø180 mm = 15.000 Pieces/Reel







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